

BYT13-600 - BYT13-1000

High-reliability discrete products and engineering services since 1977

FAST RECOVERY RECTIFIER DIODES

FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

Symbol	Parame	Value	Unit	
I _{FRM}	Repetitive peak forward current $t_p \le 20 \mu S$		50	А
I _{F(AV)}	Average forward current *	T _A = 55°C δ = 0.5	3	А
IFSM	Surge non-repetitive forward current	t _p = 10ms sinusoidal	100	А
P _{tot}	Power dissipation * T _A = 55°C		3.75	W
T _{stg} Tj	Storage and junction temperature range	-40 to +150	°C	
TL	Maximum lead temperature for soldering du	230	°C	
R _{th (j-a)}	Junction-ambient *		25	°C/W

Symbol	Parameter	BYT13-			Unit	
Symbol	Farameter	600	800	1000	onit	
V _{RRM}	Repetitive peak reverse voltage	600	800	1000	V	

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

Symbol	Test Conditions		Min.	Тур.	Max.	Unit
I _R	T ₁ = 25°C	$V_R = V_{RRM}$			20	μΑ
VF	IJ = 25 C	$I_F = 3A$			1.3	V

RECOVERY CHARACTERISTICS

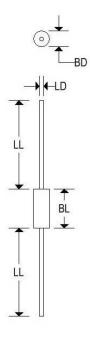
symbol	Test Conditions			Min.	Тур.	Max.	Unit	
t _{rr}	T _J = 25°C	$I_{\rm F} = 0.5 A$	$I_R = 1A$	I _{rr} = 0.25A			150	ns



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MECHANICAL CHARACTERISTICS

Case	DO-201AD	
Marking	Body painted, alpha-numeric	
Polarity	Cathode band	



	DO-201AD						
	Inc	Millim	meters				
	Min	Max	Min	Max			
BD	0.190	0.209	4.826	5.309			
BL	0.285	0.375	7.240	9.530			
LD	0.048	0.052	1.219	1.321			
LL	1.000	(7)	25.400	17			

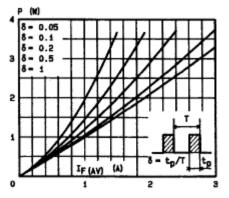
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Figure 1. Maximum average power dissipation versus average forward current.



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Figure 2. Average forward current versus ambient temperature.

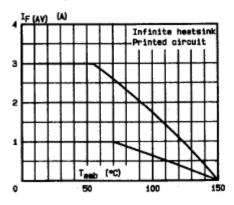
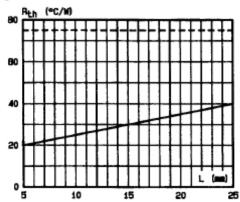


Figure 3. Thermal resistance versus lead length.





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Figure 4. Transient thermal impedance junction-ambient for mounting $n^{\circ}2$ versus pulse duration (L = 10 mm).

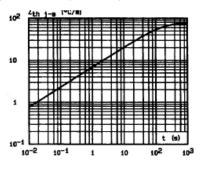


Figure 5. Peak forward current versus peak forward voltage drop (maximum values).

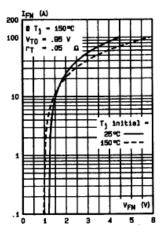


Figure 6. Capacitance versus reverse applied voltage

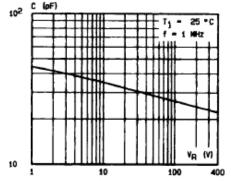


Figure 7. Non repetitive surge peak current versus number of cycles

